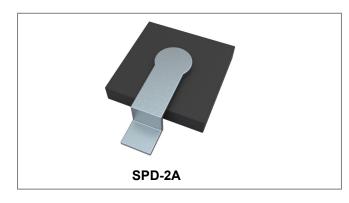


60SPB060/A

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# 60SPB060/A Power Surface Mount Schottky Rectifier



### Features

- 150 °C T<sub>J</sub> operation
- Low forward voltage drop
- High surge capacities
- High frequency operation
- Guaranteed reverse avalanche capability
- Low profile surface mount package
- Baseplate: Pure Sn plated; Terminals: Pure Sn plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### **Schematic & Pin Configuration**



### **Applications**

- Switching power supply
- Redundant power subsystems
- Reverse battery protection
- Converters
- Many other high current AC/DC power supplies

### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	60	V
Average Rectified Forward Current	IF (AV)	50% duty cycle @T <sub>c</sub> =116°C, rectangular wave form	60	А
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3 ms, half Sine pulse	860	А
Non-Repetitive Avalanche Energy	E <sub>AS</sub>	TJ=25℃, IAS=8.0A, L=1.7mH	54	mJ
Repetitive Avalanche Current	l <sub>ar</sub>	$\begin{array}{l} I_{AS} \mbox{ decaying linearly to 0 in 1} \mu sec \\ Frequency limited by T_J max. V_A = 1.5 \\ \times V_R \end{array}$	8.0	А

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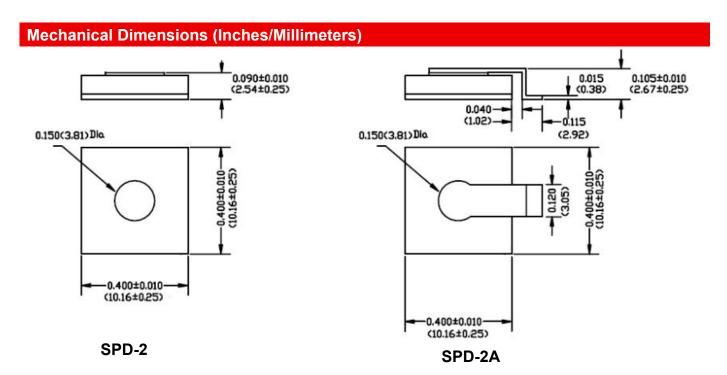
## **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop *	V <sub>F1</sub>	@ 60A, Pulse, T <sub>J</sub> = 25 °C	0.58	0.60	V
	V <sub>F2</sub>	@ 60A, Pulse, T <sub>J</sub> = 125 °C	0.51	0.57	V
Reverse Current*	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , Pulse, T <sub>J</sub> = 25 °C	0.4	6	mA
	I <sub>R2</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , Pulse, T <sub>J</sub> = 125 °C	200	420	mA
Junction Capacitance	Ст	@V <sub>R</sub> = 5V, T <sub>C</sub> = 25 °C f <sub>SIG</sub> = 1MHz	2000	2400	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

\* Pulse width < 300 µs, duty cycle < 2%

## **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	$R_{ ext{ heta}JC}$	DC operation	0.37	°C/W
Approximate Weight	wt	-	1.1	g



### Suffix "R" Denotes Reversed Polarity

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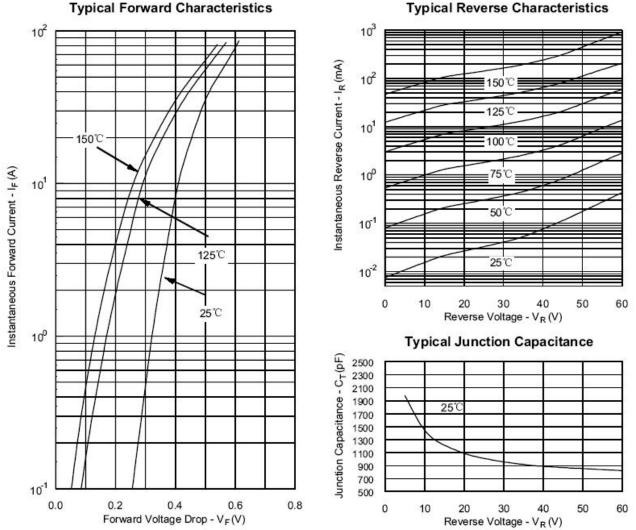


# 60SPB060/A

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### **Ratings and Characteristics Curves**



# Typical Reverse Characteristics

#### **Ordering Information**

Device	Package	Shipping	
60SPB060(A)	SPD-2A(Pb-Free)	100pcs/ box	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

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